

LETTERS

High-resolution Si and P *K*- and *L*-edge XANES spectra of crystalline SiP_2O_7 and amorphous $\text{SiO}_2\text{-P}_2\text{O}_5$

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ABSTRACT

Si and P *K*- and *L*-edge XANES spectra of crystalline SiP_2O_7 (*c*- SiP_2O_7) and amorphous $\text{SiO}_2\text{-P}_2\text{O}_5$ (*a*- $\text{SiO}_2\text{-P}_2\text{O}_5$) are reported using synchrotron radiation and interpreted using molecular orbital considerations. The Si spectra are consistent with ^{29}Si in *c*- SiP_2O_7 and with ^{29}Si in *a*- $\text{SiO}_2\text{-P}_2\text{O}_5$ (25 mol% P_2O_5). The resolution of near-edge features in the *SiL*-edge spectrum of the crystalline material is unprecedented. These spectra show definitively that Si XANES spectroscopy is a powerful technique for determining ^{29}Si and ^{31}Si in amorphous samples.

INTRODUCTION

Silicon diphosphate (*c*- SiP_2O_7) is one of several compounds in which Si has been shown to be sixfold coordinated with O at atmospheric pressure, and *c*- SiP_2O_7 has three different modifications: a cubic *Pa*3 phase and monoclinic *P2*₁/*c* and *P2*₁/*n* phases (Liebau, 1985). The IR and Raman spectra of cubic and monoclinic *c*- SiP_2O_7 were measured and interpreted by normal coordinate analyses using a modified valence force field (Chakraborty et al., 1987). The ^{29}Si MAS NMR spectra of *c*- SiP_2O_7 have also been reported (Thomas et al., 1983; Mudrakovskii et al., 1985; Grimmer et al., 1986; Stebbins and Kanzaki, 1991). The structure of glasses in the $\text{SiO}_2\text{-P}_2\text{O}_5$ system were studied using IR (Wong and Angell, 1976) and Raman spectra (Mysen et al., 1981; Shibata et al., 1981) and ^{29}Si MAS NMR spectra (Weeding et al., 1985; Sekiya et al., 1988). The energy shifts of the *SiK* α X-ray emission lines in *c*- SiP_2O_7 and $\text{SiO}_2\text{-P}_2\text{O}_5$ glasses were calculated by a SSC-DV- $X\alpha$ MO method (Okura et al., 1990).

We report high-resolution Si and P *K*- and *L*-edge XANES spectra of *c*- SiP_2O_7 and $\text{SiO}_2\text{-P}_2\text{O}_5$ glass using

synchrotron radiation. Our purposes are to interpret the XANES spectra within an MO framework and to show that XANES provides a sensitive probe for determining the Si coordination environment in amorphous materials such as *a*- $\text{SiO}_2\text{-P}_2\text{O}_5$.

EXPERIMENTAL METHODS

The *c*- SiP_2O_7 sample was synthesized by reacting high-purity SiO_2 and excess H_3PO_4 in an open silica-glass tube at about 950 °C and identified as a monoclinic *P2*₁/*n* phase by X-ray powder diffraction. $\text{SiO}_2\text{-P}_2\text{O}_5$ glasses were prepared by melting *c*- SiP_2O_7 at 1550 °C in a small Pt disk and quenching in air and H_2O . However, P_2O_5 was lost from our glass preparations during melting. Glass compositions were determined by electron microprobe analysis (EMPA). The spectra presently are from a glass with 75 mol% SiO_2 and 25 mol% P_2O_5 determined by EMPA.

The *SiK*- and *PK*-edge XANES spectra were measured using a double-crystal monochromator (DCM) of InSb (111) with synchrotron radiation. The energy resolution for the DCM is about 0.8 eV at 1840 eV. The *SiL*- and

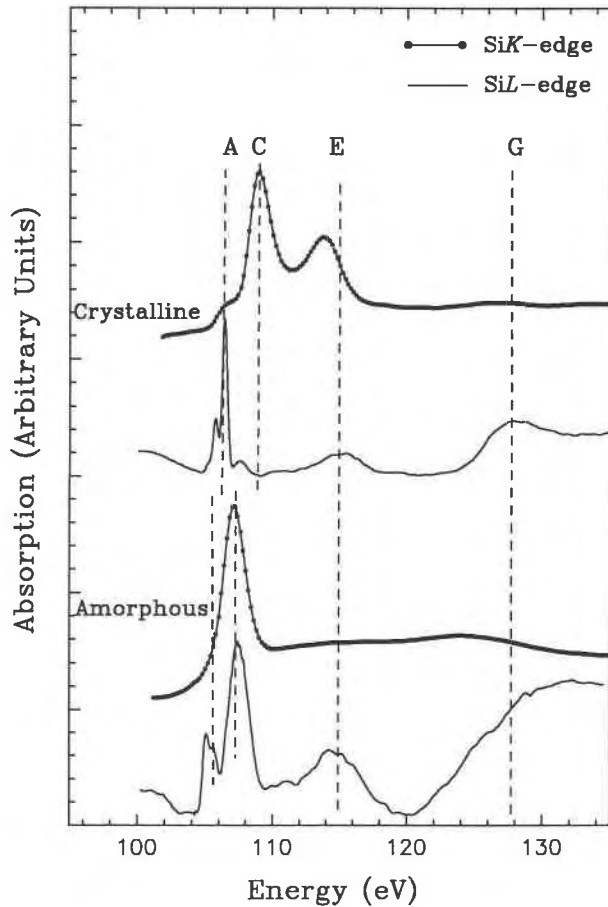


Fig. 1. SiK- and SiL-edge XANES spectra of c-SiP₂O₇ and a-SiO₂-P₂O₅.

PL-edge spectra were collected on the Grasshopper beam line employing a grazing incidence monochromator and a grating of 1800 g/mm (Bancroft, 1992). The resolution for the Grasshopper monochromator is about 0.1 eV at 100 eV. Both K- and L-edge spectra were recorded by total electron yield (TEY).

RESULTS AND DISCUSSION

Figure 1 shows the SiK- and SiL-edge XANES spectra of c-SiP₂O₇ and a-SiO₂-P₂O₅. The SiL-edge spectra are shown by the solid lines, and the SiK-edge spectra are shown by the solid lines with dots. The SiK- and SiL-edge spectra are aligned on a common scale by the SiK α_1 X-ray emission energy at 1740.0 eV, which corresponds to the Si 2p_{3/2} → 1s transition. The peak position and assignments are given in Table 1, in which ΔE for the SiK-edge spectra is the difference between each peak and the SiK α_1 X-ray emission energy at 1740 eV. SiK- and SiL-edge XANES spectra of c-SiP₂O₇ are essentially similar to those for stishovite (Li et al., 1993), characteristic of ²⁸Si. The line width of peak A in the SiL-edge spectrum is about 0.38 eV, which is the best resolution ever reported for solid state samples, to our knowledge. Peak A in the SiL-edge spectrum is assigned to the dipole-allowed transition of Si 2p electrons to a 3s-like a_{1g} state (Tossell, 1975a; Iguchi, 1977). This state is split by about 0.65 eV due to the spin-orbit interaction of Si 2p orbitals. Peak C is attributable to the transition of Si 2p electrons to a 3p-like t_{1u} state; it is weak because this transition is dipole-forbidden in an octahedral field. Peaks E and G are assigned to transitions of Si 2p electrons to empty Si 3d orbitals, the so-called shape resonance (Li et al., 1993). Because the t_{2g} state is favored in energy over the e_g state in the octahedral crystal field, peak E is assigned to the t_{2g} state, and peak G to the e_g state.

Peaks A, C, E, and G in the SiK-edge spectrum align reasonably well with the corresponding peaks in the SiL-edge spectrum and are also comparable with AlK-edge spectra of corundum (McKeown et al., 1985). Peak A is assigned to the transition of Si 1s electrons to a 3s-like a_{1g} state; it is weak because this transition is forbidden in the octahedral crystal field. Peak C is attributed to the dipole-allowed transition of Si 1s electrons to the 3p-like t_{1u} state. Peaks E and G are assigned to transitions of Si 1s electrons to the t_{2g} and e_g states, respectively, or so-called symmetry-forbidden shape resonances (Dehmer, 1972; Ferrett et al., 1986). Peak E becomes strong, but peak D, which was assigned to multiple scattering in the

TABLE 1. Assignments for SiK- and SiL-edge XANES spectra of c-SiP₂O₇ and a-SiP₂O₇.

	SiK edge			SiL edge	
	Peaks (eV)*	ΔE (eV)	Assignments	Peaks (eV)*	Assignments
c-SiP₂O₇					
A	1846.2	106.2	Si 1s → 3s-like a _{1g}	105.93	Si 2p _{3/2} → 3s-like a _{1g}
				106.59	Si 2p _{1/2} → 3s-like a _{1g}
C	1848.9	108.9	Si 1s → 3p-like t _{1u}	107.76	Si 2p → 3p-like t _{1u}
E	1853.7	113.7	Si 1s → 3d-like t _{2g}	115.2	Si 2p → 3d-like t _{2g}
G	1866.3	126.3	Si 1s → 3d-like e _g	128.2	Si 2p → 3d-like e _g
a-SiO₂-P₂O₅					
A	1844.6	104.6	Si 1s → 3s-like a ₁	105.23	Si 2p _{3/2} → 3s-like a ₁
				105.84	Si 2p _{1/2} → 3s-like a ₁
C	1846.9	106.9	Si 1s → 3p-like t ₂	107.64	Si 2p → 3p-like t ₂
E	1854.3	114.3	Si 1s → 3d-like e	114.9	Si 2p → 3d-like e
G	1863.7	123.7	Si 1s → 3d-like t ₂	129.8	Si 2p → 3d-like t ₂

* The reading error is ± 0.1 eV.

stishovite *K*-edge spectrum (Li et al., 1993), disappears, probably indicating that peak E includes a significant contribution from the multiple scattering of the more distant atom shells. Other peaks, attributed to the multiple scattering in the stishovite spectra (Li et al., 1993), are weak in the c-SiP₂O₇ spectra.

Just as the Si*K*- and Si*L*-edge spectra of c-SiP₂O₇ are very similar to those of stishovite, the Si*K*- and Si*L*-edge spectra of a-SiO₂-P₂O₅ are very similar to the corresponding spectra of α quartz (Li et al., 1993). In particular, peak C in the Si*K*-edge spectra shifts by 2.0 eV, from 1848.9 eV for c-SiP₂O₇ to 1846.9 eV for a-SiO₂-P₂O₅. This is very convincing evidence for ¹⁴⁹Si in a-SiO₂-P₂O₅, in good agreement with MAS NMR results from Weeding et al. (1985).

The Si*K*- and Si*L*-edge XANES spectra of a-SiO₂-P₂O₅ can be readily assigned according to the MO scheme for a tetrahedral crystal field. In the Si*L*-edge spectrum, peak A is assigned to the dipole-allowed transition of Si 2p electrons to a 3s-like a₁ state (Tossell, 1975b; Iguchi, 1977), and its splitting of about 0.61 eV is apparently due to the spin-orbit interaction of Si 2p orbitals. Peak C is attributed to the transition of Si 2p electrons to a 3p-like t₂ state; the p \rightarrow p transition is dipole-allowed in the tetrahedral field (Hansen et al., 1992), and consequently, peak C is very strong. Peaks E and G are attributed to the transition of Si 2p electrons to empty Si 3d states (the shape resonances). In a tetrahedral field, the Si 3d orbitals are split into t₂ and e sets, and the e set is more favored in energy, so that peak E is assigned to the transition of Si 2p electrons to the e states, and the peak G to the t₂. Peaks in the Si*K*-edge spectra of a-SiO₂-P₂O₅ are assigned as follows: peak A, due to the dipole-forbidden transition Si 1s \rightarrow 3s-like a₁, is too weak to be observed; peak C is assigned to the dipole-allowed transition Si 1s \rightarrow 3p-like t₂; and peaks E and G are assigned to transitions of Si 1s \rightarrow 3d-like e and t₂, respectively, the so-called symmetry-forbidden shape resonances. Also, the features due to the multiple scattering effect from the more distant atom shells in the α quartz spectra essentially disappear, partly related to the short-range structure in the vitreous sample.

Figure 2 shows PK- and PL-edge XANES spectra of c-SiP₂O₇ and a-SiO₂-P₂O₅. The PL-edge spectra are shown as solid lines, and the PK-edge spectra are shown as solid lines with dots. The PK- and PL-edge spectra are aligned on a common scale by the PK α X-ray emission energy at 2013.7 eV. The peak assignments are similar to Si*K*- and Si*L*-edge spectra of a-SiO₂-P₂O₅. PK- and PL-edge spectra indicate that the local structure of P in both c-SiP₂O₇ and a-SiO₂-P₂O₅ is tetrahedral. However, compared with the Si*L*-edge spectrum, peaks A and C are not resolved in the PL-edge spectrum for c-SiP₂O₇, and peak G is very broad. For a-SiO₂-P₂O₅, peaks A and C (even the spin-orbit splitting of peak A) are very well resolved, and peak G is much sharper. These results indicate a marked change in the structural state of P in the a-SiO₂-P₂O₅, and these changes will be discussed at length elsewhere.

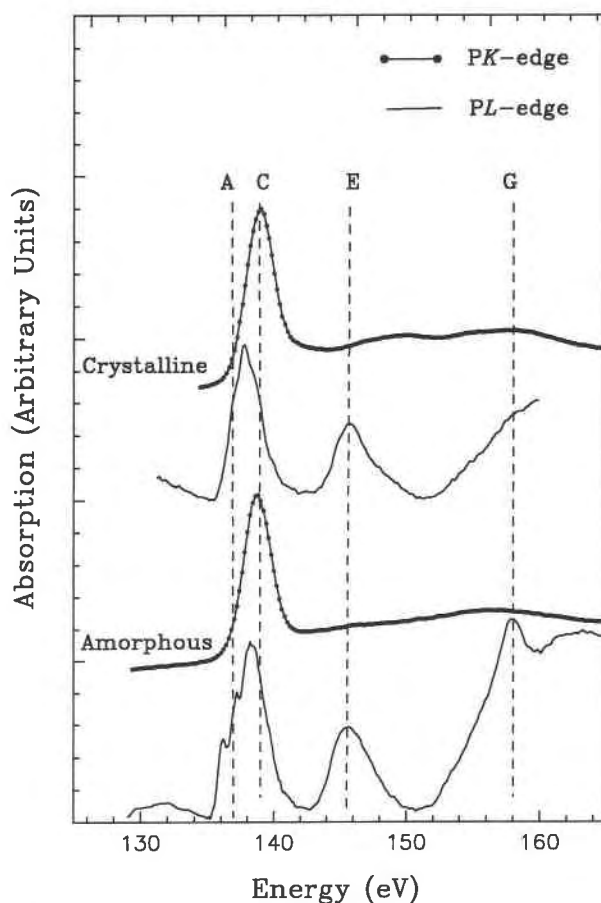


Fig. 2. PK- and PL-edge XANES spectra of c-SiP₂O₇ and a-SiO₂-P₂O₅.

In general, as shown in Figures 1 and 2, XANES features are aligned very well in both *K*- and *L*-edge spectra, and the relative intensities are also in good agreement with those expected from the dipole selection rules. The small shift for the equivalent feature in the *K*- and *L*-edge spectra is probably related to the relaxation of inner-shell 1s and 2p holes, even though the shift due to the inner-shell 1s and 2p relaxation of Si 1s is <1 eV (Bozek et al., 1987).

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